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NCE P-Channel Enhancement Mode Power MOSFET

Description

The NCE60P18AK uses advanced trench technology and design to provide excellent $R_{DS(ON)}$ with low gate charge .This device is well suited for high current load applications.

General Features

V_{DS} =-60V,I_D =-18A

 $R_{DS(ON)}$ <65m Ω @ V_{GS} =-10V

 $R_{DS(ON)}$ <85m Ω @ V_{GS} =-4.5V

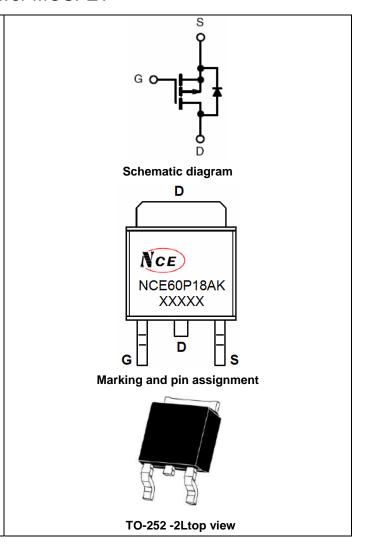
- High density cell design for ultra low Rdson
- Fully characterized avalanche voltage and current
- Good stability and uniformity with high E_{AS}
- Excellent package for good heat dissipation

Application

- High side switch for full bridge converter
- DC/DC converter for LCD display

100% UIS TESTED!

100% ΔVds TESTED!



Package Marking and Ordering Information

Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
NCE60P18AK	NCE60P18AK	TO-252-2L	-	-	-

Absolute Maximum Ratings (T_C=25 ℃unless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	V _{DS}	-60	V
Gate-Source Voltage	V _{GS}	±20	V
Drain Current-Continuous	I _D	-18	Α
Drain Current-Continuous(T _C =100 °C)	I _D (100℃)	-12.7	Α
Pulsed Drain Current	I _{DM}	-72	Α
Maximum Power Dissipation	P _D	60	W
Derating factor		0.4	W/℃
Single pulse avalanche energy (Note 5)	E _{AS}	50	mJ
Operating Junction and Storage Temperature Range	T_{J} , T_{STG}	-55 To 175	$^{\circ}\!\mathbb{C}$



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NCE60P18AK

Thermal Characteristic

Thermal Resistance, Junction-to-Case ^(Note 2)	R _{eJC}	2.5	°C/W	Ī
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Electrical Characteristics (T_C=25°C unless otherwise noted)

Parameter	Symbol	Condition	Min	Тур	Max	Unit
Off Characteristics			•			
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V I _D =-250μA	-60	-	-	V
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =-60V,V _{GS} =0V	-	-	-1	μΑ
Gate-Body Leakage Current	I _{GSS}	V_{GS} =±20 V , V_{DS} =0 V	-	-	±100	nA
On Characteristics (Note 3)			•			
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}$, $I_D=-250\mu A$	-1	-1.5	-2.2	V
Drain Source On State Desistance	В	V _{GS} =-10V, I _D =-12A	-	49	65	mΩ
Drain-Source On-State Resistance	$R_{DS(ON)}$	V _{GS} =-4.5V, I _D =-8A	-	58	85	mΩ
Forward Transconductance	g FS	V _{DS} =-5V,I _D =-12A	-	10	-	S
Dynamic Characteristics (Note4)			•			
Input Capacitance	C _{lss}	\/ 20\/\/ 0\/	-	1630.7	-	PF
Output Capacitance	C _{oss}	V_{DS} =-30V, V_{GS} =0V, F=1.0MHz	-	90.6	-	PF
Reverse Transfer Capacitance	C _{rss}	F=1.UMHZ	-	77.3	-	PF
Switching Characteristics (Note 4)			•			
Turn-on Delay Time	$t_{d(on)}$		-	11	-	nS
Turn-on Rise Time	t _r	V_{DD} =-30V, R_L =1.5 Ω ,	-	14	-	nS
Turn-Off Delay Time	t _{d(off)}	V_{GS} =-10 V , R_{G} =3 Ω	-	33	-	nS
Turn-Off Fall Time	t _f		-	13	-	nS
Total Gate Charge	Qg	V 00 L 40A	-	37.6		nC
Gate-Source Charge	Q _{gs}	V_{DS} =-30, I_{D} =-12A, V_{GS} =-10V	-	4.3		nC
Gate-Drain Charge	Q_{gd}	V _{GS} =-10V	-	7.2		nC
Drain-Source Diode Characteristics			•			
Diode Forward Voltage (Note 3)	V _{SD}	V _{GS} =0V,I _S =-12A	-		-1.2	V
Diode Forward Current (Note 2)	Is		-	-	-18	А
Reverse Recovery Time	t _{rr}	TJ = 25°C, IF =- 12A	-	35		nS
Reverse Recovery Charge	Qrr	$di/dt = -100A/\mu s^{(Note3)}$	-	38		nC
Forward Turn-On Time	t _{on}	Intrinsic turn-on time is negl	igible (tur	n-on is do	minated by	/ LS+LD)

Notes:

- $\textbf{1.} \ \textbf{Repetitive Rating: Pulse width limited by maximum junction temperature.}$
- 2. Surface Mounted on FR4 Board, t ≤ 10 sec.
- 3. Pulse Test: Pulse Width ≤ 300µs, Duty Cycle ≤ 2%.
- 4. Guaranteed by design, not subject to production
- **5.** E_{AS} condition: Tj=25 $^{\circ}$ C,V_{DD}=-30V,V_G=-10V,L=0.5mH,Rg=25 Ω

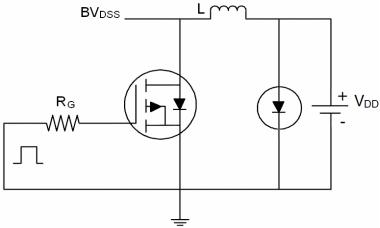
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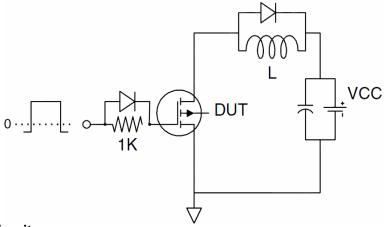
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Test Circuit

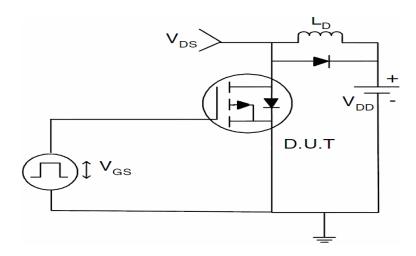
1) E_{AS} Test Circuit



2) Gate Charge Test Circuit



3) Switch Time Test Circuit





Typical Electrical and Thermal Characteristics (Curves)

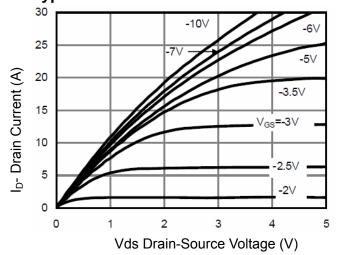


Figure 1 Output Characteristics

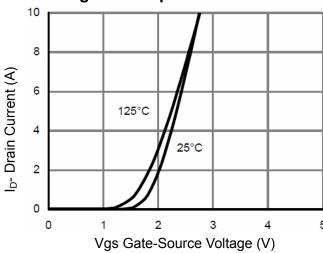


Figure 2 Transfer Characteristics

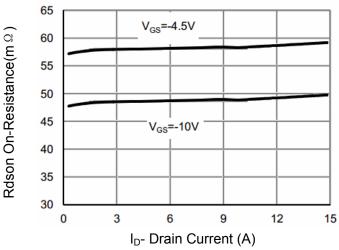


Figure 3 Rdson- Drain Current

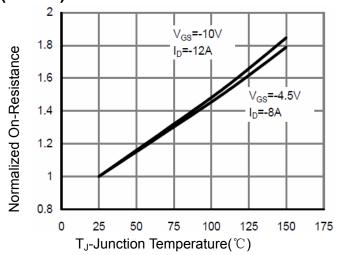
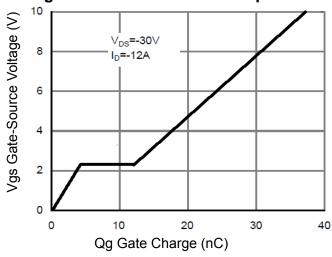


Figure 4 Rdson-Junction Temperature



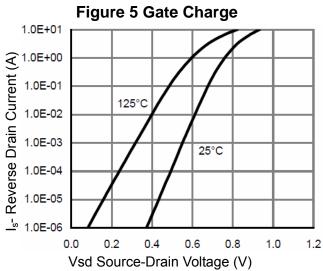
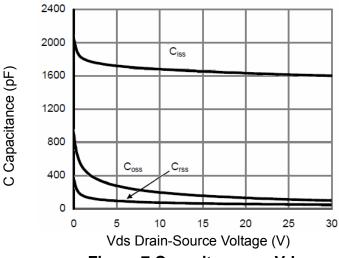


Figure 6 Source- Drain Diode Forward



Power Dissipation (W) T_J -Junction Temperature($^{\circ}$ C)

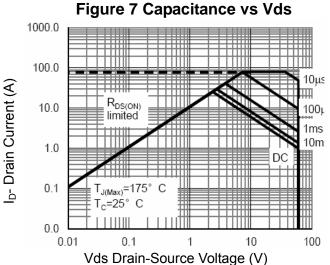


Figure 9 Power De-rating Ip- Drain Current (A)

Figure 8 Safe Operation Area

 T_J -Junction Temperature(°C) Figure 10 ID Current De-rating

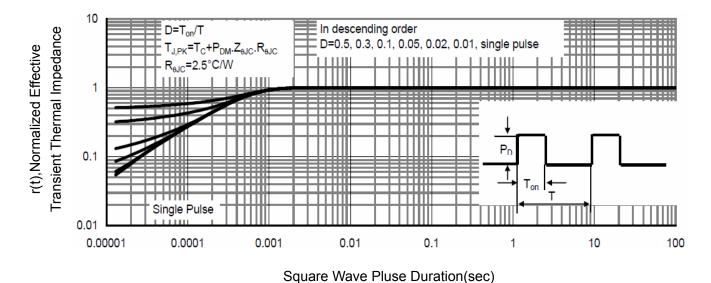
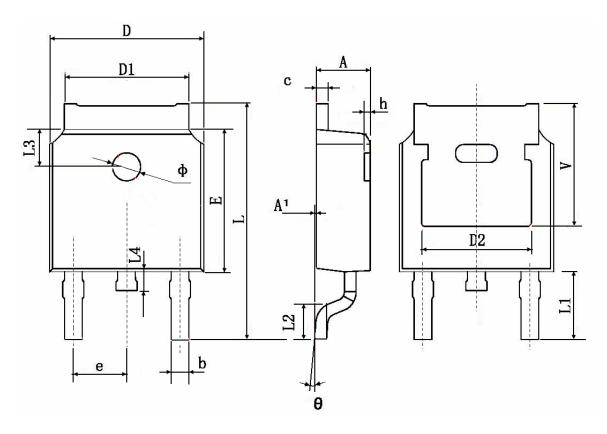


Figure 11 Normalized Maximum Transient Thermal Impedance

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TO-252 Package Information



O	Dimensions	In Millimeters	Dimensions In Inches			
Symbol	Min.	Max.	Min.	Max.		
А	2.200	2.400	0.087	0.094		
A1	0.000	0.127	0.000	0.005		
b	0.660	0.860	0.026	0.034		
С	0.460	0.580	0.018	0.023		
D	6.500	6.700	0.256	0.264		
D1	5.100	5.460	0.201	0.215		
D2	4.830	TYP.	0.190 TYP.			
E	6.000	6.200	0.236	0.244		
е	2.186	2.386	0.086	0.094		
L	9.800	10.400	0.386	0.409		
L1	2.900	2.900 TYP.		TYP.		
L2	1.400	1.700	0.055	0.067		
L3	1.600	TYP.	0.063	TYP.		
L4	0.600	1.000	0.024	0.039		
Ф	1.100	1.300	0.043	0.051		
θ	0°	8°	0°	8°		
h	0.000	0.300	0.000	0.012		
V	5.350	TYP.	0.211	TYP.		



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